



Low-Voltage, 4:1 Mux/Demux with Low-Swing Control Inputs

Features

- → CMOS Technology for Analog Applications
- → Low-swing control inputs
- → Low On-Resistance
- → Wide V_{DD} Range: 1.8V to 3.3V
- → Rail-to-Rail Signal Range
- → Near zero propagation delay
- → Fast Switching Speed
- → Ultra-low quiescent power
- → High Off Isolation: -95dB @ 100kHz
- → Crosstalk Rejection Reduces Signal Distortion: -90dB @ 100kHz
- → Packaging (Pb-free & Green):
 - -10-contact TQFN (1.6×1.3)

Truth Table(1)

Enable	Select		Function	
EN	S_1	S_0	Function	
L	X	X	Y=A _x , Hi-Z	
Н	L	L	$Y = A_0; A_1, A_2, A_3 = Hi-Z$	
Н	L	Н	$Y = A_1; A_0, A_2, A_3 = Hi-Z$	
Н	Н	L	$Y = A_2; A_{0}, A_{1}, A_3 = Hi-Z$	
Н	Н	Н	$Y = A_3; A_{0}, A_{1}, A_2 = Hi-Z$	

Pin Description

Pin Name	Description
A_{N}	Data I/O
S ₀₋₁	Select Inputs
EN	Enable
Y	Data I/O Common
GND	Ground
V_{DD}	Power

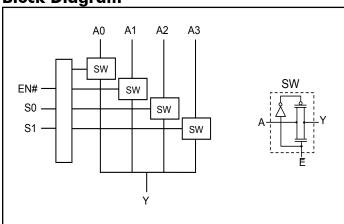
Description

Diodes' PI3A114-A is a one-to-four bidirectional multiplier-demultiplier. Specified over a wide operating power supply voltage of 1.8 to 3.3V, the PI3A114-A offer good signal linearity.

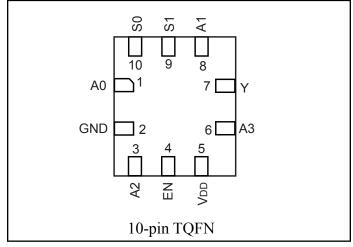
The PI3A114-A offers low-swing input voltage on the EN, S1 and S0 inputs allowing the device to operate at 3.3V, and pass 3.3V channel data, while being controlled from a 1.8V device.

Block Diagram

1



Pin Configuration (top view)







Absolute Maximum Ratings(1)

Supply Voltage V _{DD}	0.5V to 4.2V
Control Input Voltage (VINx)	0V to 5V
DC Input Voltage (V _{INPUT}) ⁽²⁾	0.5V to 4.2V
Continuous Current NO_NC_COM	
Peak Current NO_NC_COM_	
(pulsed at 1ms 50% duty cycle)	±400mA
Peak Current NO NC COM	
(pulsed at 1ms 10% duty cycle)	±500mA
Storage Temperature Range (T _{STG})	65°C to +150°C
Junction Temperature under Bias (T _J)	
Junction Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C
Power Dissipation (P _D) @ +85°C	250mW

Recommended Operating Conditions⁽³⁾

Supply Voltage Operating (V_{DD}) 1.8V to 3.3V $\pm 5\%$
Control Input Voltage (V_{IN})
Switch Input Voltage (V_{INPUT})0.3V to V_{DD}
Operating Temperature $(T_A) \dots -40^{\circ}C$ to $+85^{\circ}C$
Input Rise and Fall Time (t _r ,t _f)
Control Input $V_{DD} = 2.3V - 3.6V \dots 0ns/V$ to $10ns/V$
Thermal Resistance (θ_{JA})350°C/W

Notes:

- 1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- 2. The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.
- 3. Control input must be held HIGH or LOW; it must not float.

DC Electrical Characteristics +1.8V Supply

 $(V_{DD} = 1.8V, T_A = -40^{\circ}C \text{ to } 85^{\circ}C, \text{ unless otherwise noted.})$

Parameter	Description	Test Conditions	Min.	Typ. ⁽²⁾	Max.	Units
Analog Swi	tch					
Y, Ax	Analog Signal Range		-0.3		V_{DD}	V
R _{ON}	On-Resistance	$I_Y = 100 \text{mA}, V_{IN} = 0 \text{ to } V_{DD}$			9	
$\Delta R_{ m ON}$	On-Resistance Match Between Channels	$I_{Y} = 100 \text{mA}, V_{IN} = 0.5 V_{DD}$			0.6	Ω
R _{ONF}	On-Resistance Flatness	$I_Y = 100 \text{mA}, V_{IN} = 0 \text{ to } V_{DD}$			5	
THD	Total Harmonic Distortion	Load = $100 \text{K}\Omega$, V_{IN} = $0.5 V_{DD}$, Frequency = 20Hz to 20KHz		0.03		%
Control Inp	uts ⁽¹⁾					
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	1.5			V
$V_{ m IL}$	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5		0.8	v
I_{IH}	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±1	
${ m I}_{ m IL}$	Input LOW Current	$V_{DD} = Max., V_{IN} = GND$			±1	μΑ
I _{OZH}	High Impedance Output Current	$0 \le I_N, Y_N \le V_{DD}$			±1	μιι
V _{IK}	Clamp Diode Voltage	$V_{DD} = Min., I_{IN} = -18mA$			-1.2	V

Notes:

- 1. For digital control inputs EN, S0, S1.
- 2. Typical values are at $V_{DD} = 1.8V$, $T_A = 25^{\circ}C$ ambient and maximum loading.
- 3. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 4. Measured by the voltage drop between A and Y pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (I,Y) pins.





Power Supply Characteristics +1.8V Supply

	Parameters	Description	otion Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Units
I	CC	Quiescent Power Supply Current	$V_{DD} = Max.$	$V_{IN} = GND \text{ or } V_{DD}$		0.1	9.0	μΑ

Notes:

- 1. Control inputs only; A and Y pins do not contribute to I_{CC}.
- 2. Typical values are at $V_{DD} = 1.8V$, $T_A = 25^{\circ}C$ ambient and maximum loading.
- 3. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.

DC Electrical Characteristics +3.3V Supply

 $(V_{DD} = 3.3V, T_A = -40^{\circ}C \text{ to } 85^{\circ}C, \text{ unless otherwise noted.})$

Parameter Description		Test Conditions	Min.	Typ ⁽²⁾	Max.	Units
Analog Swi	tch					
Y, Ax	Analog Signal Range		-0.3		V_{DD}	V
R _{ON}	On-Resistance	$I_Y = 100 \text{mA}, V_{IN} = 0 \text{ to } V_{DD}$			5	
$\Delta R_{ m ON}$	On-Resistance Match Between Channels	$I_{Y} = 100 \text{mA}, V_{IN} = 0.5 V_{DD}$			0.2	Ω
R _{ONF}	On-Resistance Flatness	$I_Y = 100 \text{mA}$, $V_{IN} = 0$ to V_{DD}			0.6	
THD	Total Harmonic Distortion	Load = $100 K\Omega$, V_{IN} = $0.5 V_{DD}$, Frequency = $20 Hz$ to $20 KHz$		0.03		%
Control Inpu	uts ⁽¹⁾					
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH Level	1.5			V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5		0.8	\ \ \
I_{IH}	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±1	
I_{IL}	Input LOW Current	$V_{DD} = Max., V_{IN} = GND$			±1	μΑ
I _{OZH}	High Impedance Output Current	$0 \leq I_N, Y_N \leq V_{DD}$			±1	μΛ
V _{IK}	Clamp Diode Voltage	$V_{DD} = Min., I_{IN} = -18mA$			-1.2	V

Notes:

- 1. For digital control inputs EN, S0, S1.
- 2. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at $V_{DD} = 3.3V$, $T_A = 25$ °C ambient and maximum loading.
- 3. Measured by the voltage drop between A and Y pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (I,Y) pins.

Power Supply Characteristics, 3.3V Supply

Parameters	Description	Test	Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
I_{CC}	Quiescent Power Supply Current	$V_{DD} = Max.$	$V_{IN} = GND \text{ or } V_{DD}$		0.1	9.0	μΑ

Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at $V_{DD} = 3.3V$, +25°C ambient.
- 3. Control inputs only; A and Y pins do not contribute to I_{CC}.





Switch and AC Characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
t _{ON}	Turn-On Time	V_{DD} = 2.7V, V_{IN} = 1.5V, R_L = 50 Ω , C_L = 35pF, See Test Circuit Figure 1 & 2.		5	15	
t _{OFF}	Turn-Off Time	V_{DD} = 2.7V, V_{IN} = 1.5V, R_L = 50 Ω , C_L = 35pF, See Test Circuit Figure 1 & 2.		35	50	ns
Q	Charge Injection	$COM = 0$, $R_S = 0$, $C_L = 1nF$, $V_{DD} = 3.3V$ See Test Circuit Figure 4.		15		рC
O _{IRR}	Off-Isolation	$C_L = 5 p F, R_L = 50 \Omega, f = 100 k H z,$ $V_{IN} = 1 V_{RMS}, V_{DD} = 3.3 V$ See Test Circuit Figure 5.		-95		ΠĻ
X _{TALK}	Crosstalk	$C_L = 5 pF$, $R_L = 50 \Omega$, $f = 100 kHz$, $V_{IN} = 1 V_{RMS}$, $V_{DD} = 3.3 V$ See Test Circuit Figure 6.		-90		dB
f _{3dB}	3dB Bandwidth	See Test Circuit Figure 9., V _{DD} = 3.3V		250		MHz
$t_{pd}^{(1)}$	Propogation delay	$C_L = 5pF, R_L = 500km$			0.25	ns

Note:

Capacitance

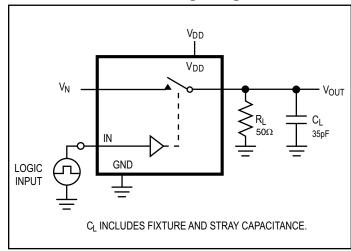
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
C _{NC (OFF)}	Off Capacitance	f = 1MHz, See Test Circuit Figure 7.		15		рF
C _{NC (ON)}	On Capacitance	f = 1MHz, See Test Circuit Figure 8.		25		pr

4

^{1.} This Parameter is not production tested.



Test Circuits and Timing Diagrams



Capacitance
Meter

f = 1 MHz

Capacitance
IN

GND

GND

GND

 V_{DD}

Figure 2. AC Waveforms

Figure 1. AC Test Circuit

Notes:

1. Unused input (NC or NO) must be grounded.

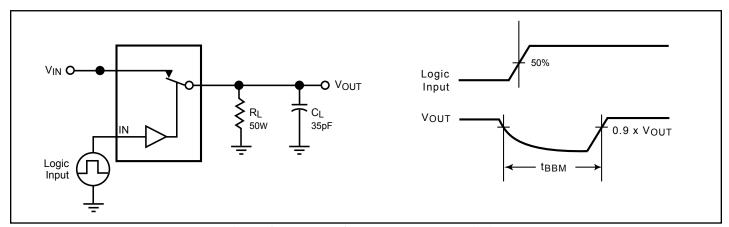


Figure 3. Break Before Make Interval Timing

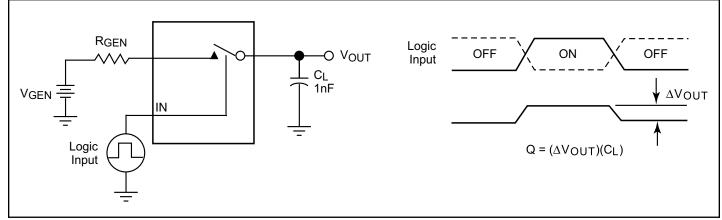


Figure 4. Charge Injection Test



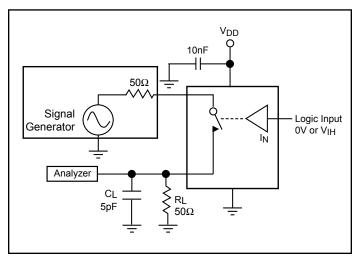


Figure 5. Off Isolation

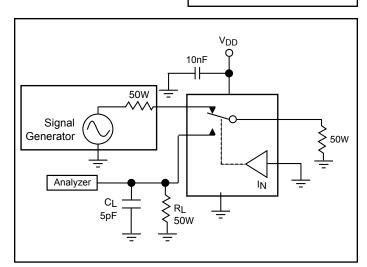


Figure 6. Crosstalk

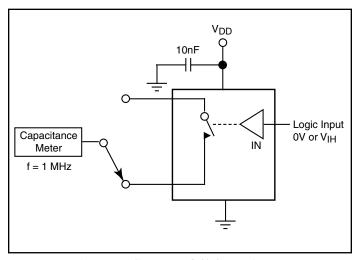


Figure 7. Channel Off Capacitance

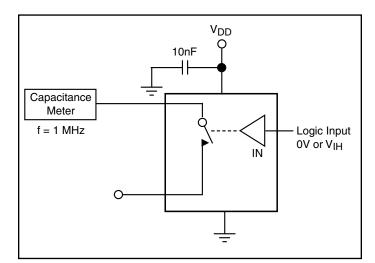


Figure 8. Channel On Capacitance

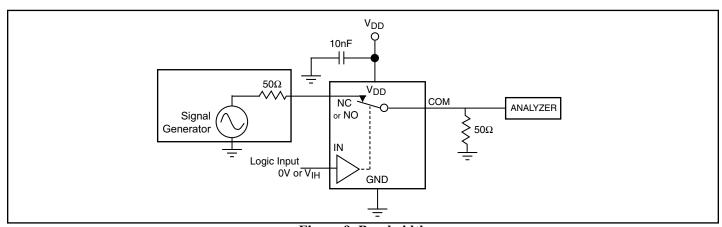
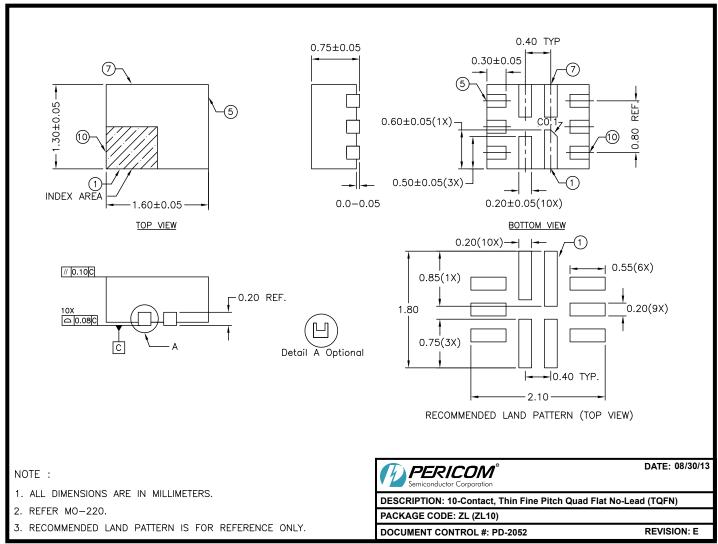


Figure 9. Bandwidth





Packaging Mechanical: 10-pin TQFN (ZL)



13-0175

For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

Ordering Information

Ordering Code	Packaging Code	Package Type	Top Mark
PI3A114-AZLEX	ZL	10-Contact, Thin Fine Pitch Quad Flat No-Lead (TQFN)	CR

Notes:

- · Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/
- E = Pb-free and Green
- X suffix = Tape/Reel





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